

<b>FORM PTO-1449</b>  <b>LIST OF PATENTS AND PUBLICATIONS FOR</b> <b>APPLICANT'S INFORMATION DISCLOSURE</b> <b>STATEMENT</b>  <b>(Use several sheets if necessary)</b>	<b>ATTY. DOCKET NO.</b>	<b>APPLICATION NO.</b>	<b>CONFIRMATION NO.</b>
	<b>200314202-1</b>		
	<b>APPLICANT</b>		
	<b>WEI, Qingqiao</b>		
	<b>FILING DATE</b>	<b>GROUP</b>	
	<b>03-23-2004</b>		

## REFERENCE DESIGNATION

## **U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
	1A	20030205078A	11-06-2003	Hasei et al.	
	1B	6,627,964B2	09-30-2003	Nakashima et al.	
	1C	20030153088A	08-14-2003	DiMeo, Jr. et al.	
	1D	20030139003A	07-24-2003	Gole et al.	
	1E	6,596,236B2	07-22-2003	DiMeo, Jr. et al.	
	1F	20030121764A	07-03-2003	Yang et al.	
	1G	20030113714A	06-19-2003	Belcher et al.	
	1H	20030089899A	05-15-2003	Lieber et al.	
	1I	20020130311A	09-19-2002	Lieber et al.	
	1J	20020117659A	08-29-2002	Lieber et al.	
	1K	6,265,222B1	07-24-2001	DiMeo, Jr. et al.	

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
	1L	WO2003046536	06-05-2003	Sony International		
	1M	EP0711410B1	03-26-1997	IBM Corp.		
	1N					
	1O					
	1P					

**OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)**

1Q	S. NAKATA et al., "Field effect transistor type NO <sub>2</sub> sensor combined with NaNO <sub>2</sub> auxiliary phase," Sensors and Actuators B 77 (2001) pp. 512-516
1R	D. BRIAND et al., "A Low-Power Micromachined MOSFET Gas Sensor," J. Microelectromechanical Systems, 9(3), Sept 2000, pp. 303-308
1S	S. TRAUTWEILER et al., "New Silicon-Based Metal-Oxide Chemical Sensors" Sensors Magazine, V16(9), Sept. 1999, p. 109 ff.

**EXAMINER**

**DATE CONSIDERED**

## PATENT APPLICATION

Sheet 1 of 3

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EXAMINER INITIAL	DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
1A	5,731,510B	03-24-1998	Jones et al.	
1B	4,020,830B	05-03-1977	Johnson et al.	
1C				
1D				
1E				
1F				
1G				
1H				
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	1L					
	1M					
	1N					
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## OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

1Q	M.B. STERN et al., "Nanochannel fabrication for chemical sensors." J. Vac. Sci. Technol. B 15(6), Nov/Dec 1997, pp. 2887-2891
1R	G. F. BLACKBURN, "Chemically sensitive field effect transistors," Ch. 26 of A. P. F. Turner et al. (eds) "Biosensors: Fundamentals and Applications," Oxford U.P., Oxford (1987) pp. 481-530
1S	I. LUNDSTROM et al., "Gas Sensors Based on Catalytic Metal-Gate Field-Effect Devices," Sensors and Actuators 10 (1986) pp. 399-421

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1L						
1M						
1N						
1O						
1P						

## OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

1Q	J. JANATA et al. "Chemically Sensitive Field Effect Transistors," Ch. 3 of H. Freiser (ed.) "Ion-Selective Electrodes in Analytical Chemistry - Vol. 2" Plenum Press, New York (1980) pp. 107-174
1R	
1S	

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